





#### 100V PNP MEDIUM POWER TRANSISTOR IN SOT89

#### **Features**

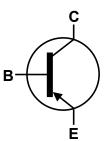
- BV<sub>CEO</sub> > -100V
- I<sub>C</sub> = -1A high Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Collector Current
- Low saturation voltage V<sub>CE(sat)</sub> < -200mV @ -250mA</li>
- Complementary NPN type: FCX493
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

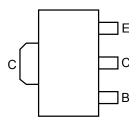
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.05 grams (Approximate)







Device Symbol



Top View Pin Out

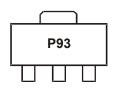
#### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX593TA	P93	7	12	1,000

Notes:

- $1.\ No\ purposely\ added\ lead.\ Fully\ EU\ Directive\ 2002/95/EC\ (RoHS)\ \&\ 2011/65/EU\ (RoHS\ 2)\ compliant.$
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



P93 = Product Type Marking Code



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	-120	V
Collector-Emitter Voltage	$V_{CEO}$	-100	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-2	Α

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1	
Power Dissipation	(Note 6)	P <sub>D</sub>	1.5	W
	(Note 7)		2.0	
	(Note 5)		125	°C/W
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	83	
	(Note 7)		60	
Thermal Resistance, Junction to Lead (Note 8)		R <sub>θJL</sub>	22	
Thermal Resistance, Junction to Case	(Note 9)	R <sub>0</sub> JC	16	
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C	

## ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

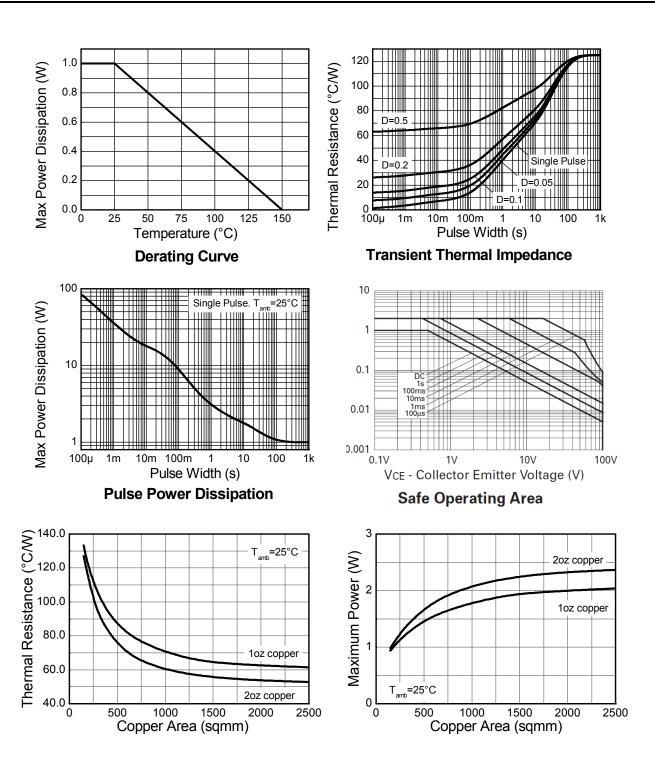
Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper. 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 9. Thermal resistance from junction to the top of the case.
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





## **Thermal Characteristics and Derating Information**







# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

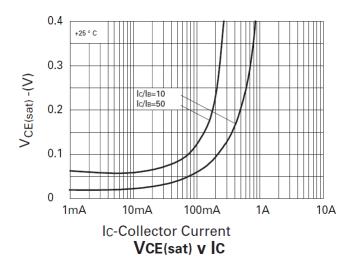
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-120	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	$BV_{CEO}$	-100	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -100V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5V
Emitter Cutoff Current	I <sub>CES</sub>	_	_	-100	nA	V <sub>CES</sub> = -100V
DC current transfer Static ratio (Note 11)	h <sub>FE</sub>	100 100 100 50	_	— 300 —	_	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -250mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -500mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>			-0.2 -0.3	V	$I_C$ = -250mA, $I_B$ = -25mA $I_C$ = -500mA, $I_B$ = -50mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	_	_	-1.1	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Turn-on Voltage (Note 11)	V <sub>BE(on)</sub>	_	_	-1.0	V	$I_C = -1 \text{mA}, V_{CE} = -5 \text{V}$
Transitional Frequency	f <sub>T</sub>	50	_	_	MHz	I <sub>E</sub> = -50mA, V <sub>CE</sub> = -10V f = 100MHz
Output capacitance	C <sub>obo</sub>	_	_	5	pF	V <sub>CB</sub> = -10V, f = 1MHz,

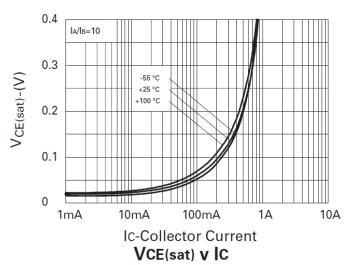
Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

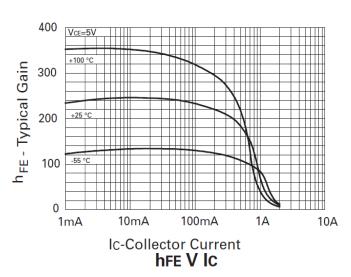


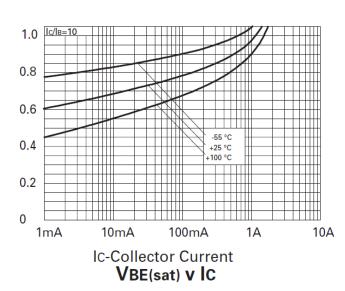


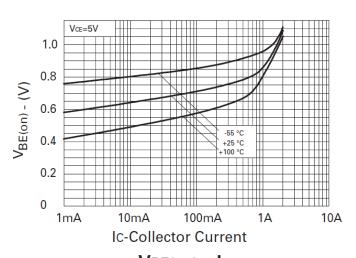
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)









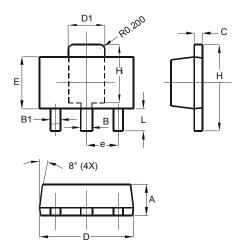






## **Package Outline Dimensions**

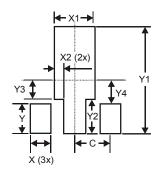
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
Ĺ	0.89	1.20		
All Dimensions in mm				

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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